



## 37 to 43 GHz GaN Power Amplifier, 35 dB Gain, +38 dBm P<sub>sat</sub>

### Description:

Model SBP-3734333538-2F2F-E1-HR is a GaN power amplifier with a typical small signal gain of 35 dB and a nominal P<sub>sat</sub> of +38 dBm across the frequency range of 37 to 43 GHz. The DC power requirement for the amplifier is +15V<sub>DC</sub>/3.7 A. The RF connectors are female 2.4 mm connectors. Other port configurations, such as V connectors and WR-22 waveguides for either the input or output port, are also available under different model numbers.



### Features:

- High Output Power
- Good Power and Gain Flatness

### Applications:

- 5G System
- Test Equipment

### Electrical Specifications:

Parameter	Minimum	Typical	Maximum
Frequency	37 GHz		43 GHz
Gain		35 dB	
P <sub>1dB</sub>		+34 dBm	
P <sub>sat</sub>		+38 dBm	
P <sub>in</sub>			+10 dBm
Input Return Loss		10 dB	
Output Return Loss		10 dB	
DC Voltage	+14 V <sub>DC</sub>	+15 V <sub>DC</sub>	+17 V <sub>DC</sub>
DC Supply Current (Under RF Drive)		3.7 A	
Supply Voltage to Fan		+12 V <sub>DC</sub>	
Specification Temperature		+25°C	
Operating Temperature	0°C		+50°C

### Mechanical Specifications:

Item	Specification
Input	2.4 mm (F)
Output	2.4 mm (F)
Bias	Solder Pin
Case Material	Aluminum
Finish	Gold Plated
Weight	17 Oz
Size	3.15" (L) X 3.15" (W) X 3.48" (H)
Outline	BK-SC-C1-H



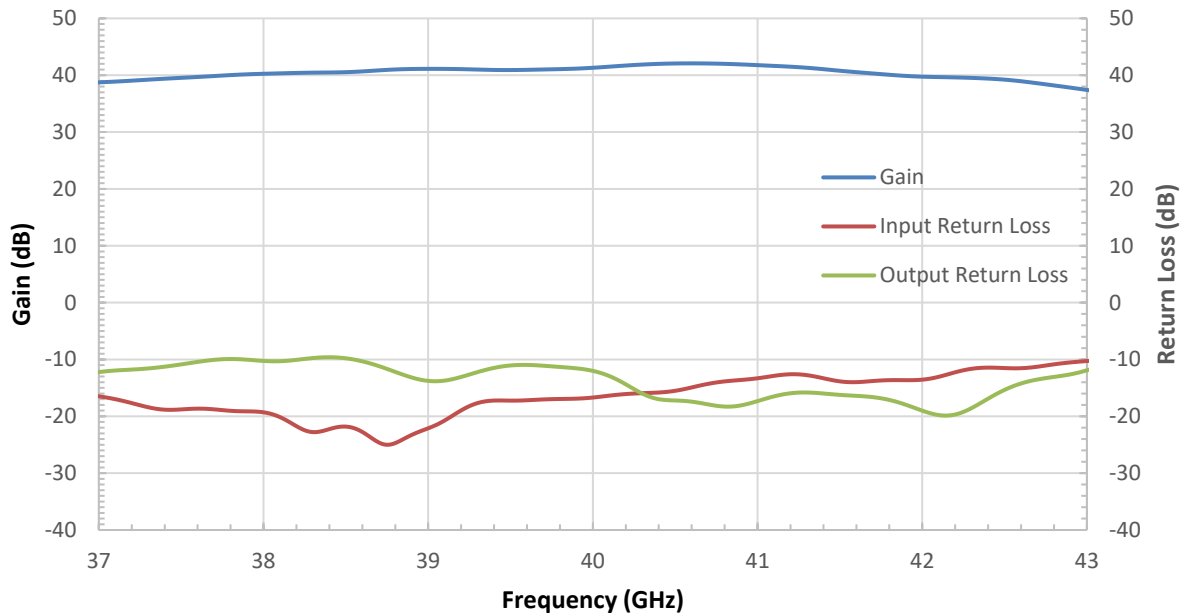


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### Test Data:

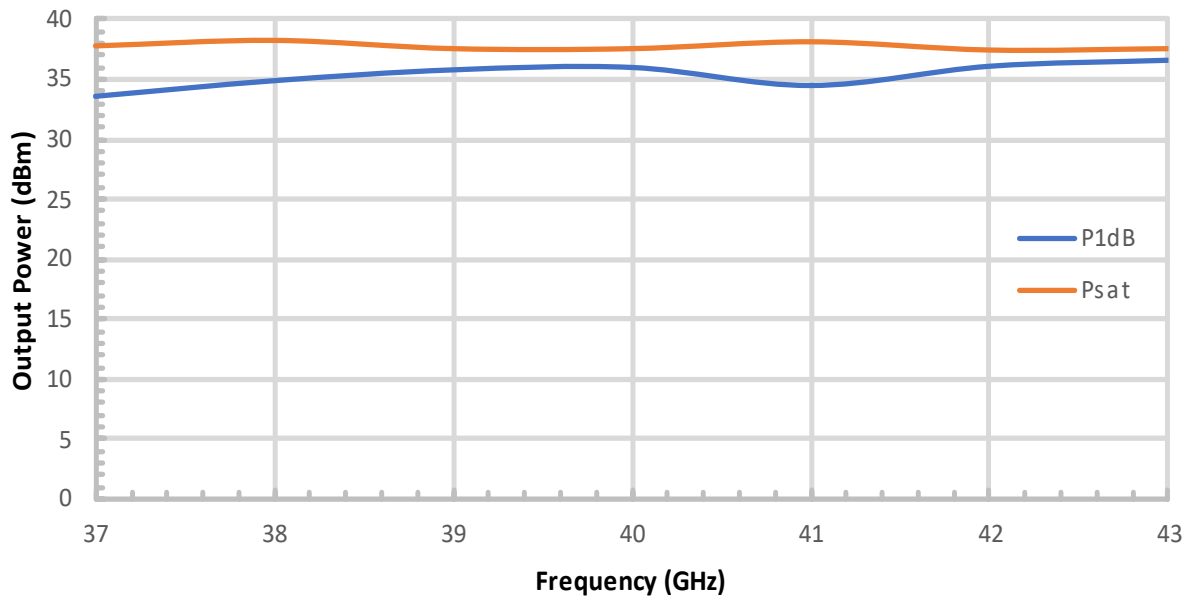
#### Gain and Return Loss vs. Frequency

Bias: +15 V<sub>DC</sub>/ 1.7 A



#### Output Power vs. Frequency

Bias: +15V<sub>DC</sub>/3.7A

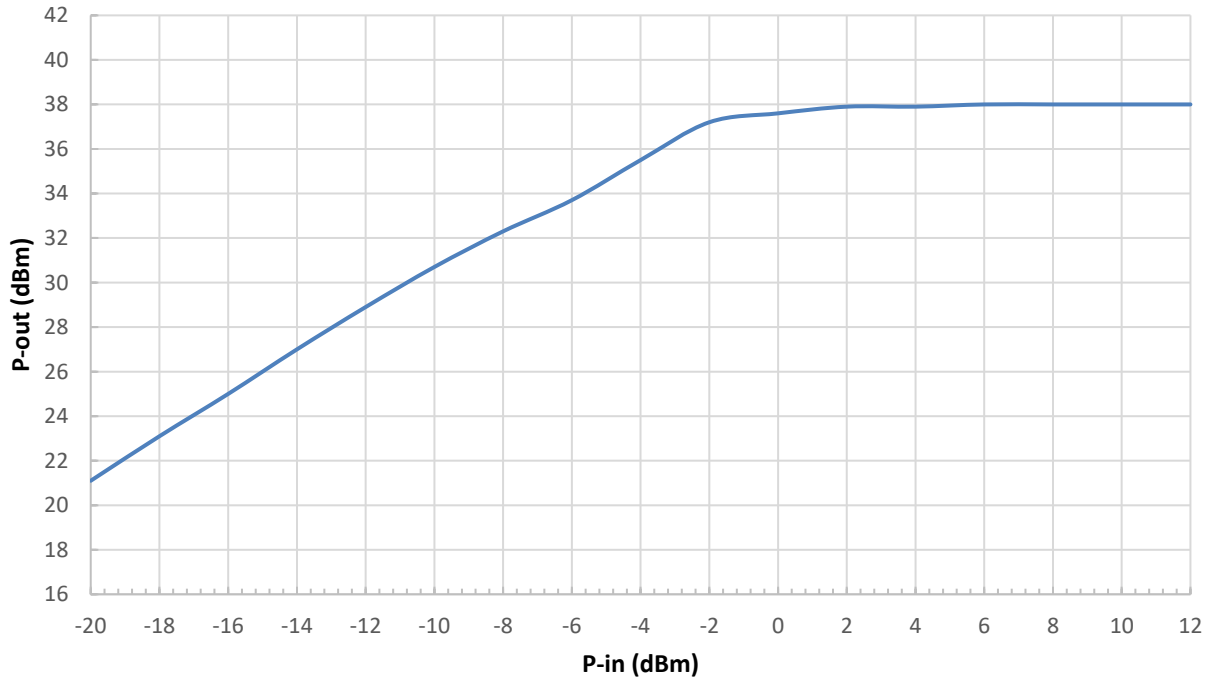




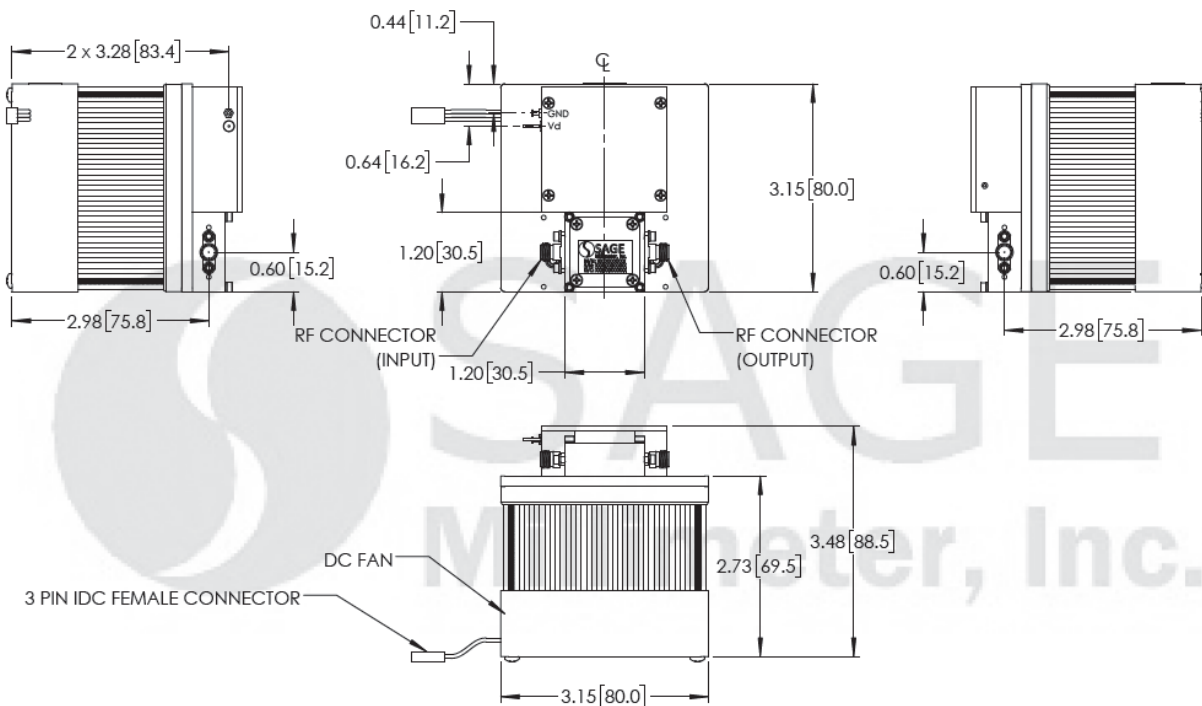
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### P-in vs. P-out

RF Input: 40 GHz



**Mechanical Outline:** (Unless otherwise specified, all dimensions are in inches [millimeters])





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### Note:

- All data presented is collected from a sample lot. Actual data may vary unit to unit.
- All testing was performed under +25 °C case temperature.
- Other mechanical configurations are available under different model numbers.
- Eravant reserves the right to change the information presented without notice.

### Caution:

- Exceeding absolute maximum ratings shown will damage the device.
- The device is static sensitive. Always follow ESD rules when working with the device.
- The case temperature of the device shall never exceed +50 °C. Use proper heatsink or fan if necessary.
- Proper torque,  $8.0 \pm 0.15$  inch-pounds ( $0.90 \pm 0.02$  Nm), should be applied. **Eravant torque wrench, model SCH-08008-S1, is highly recommended.**

